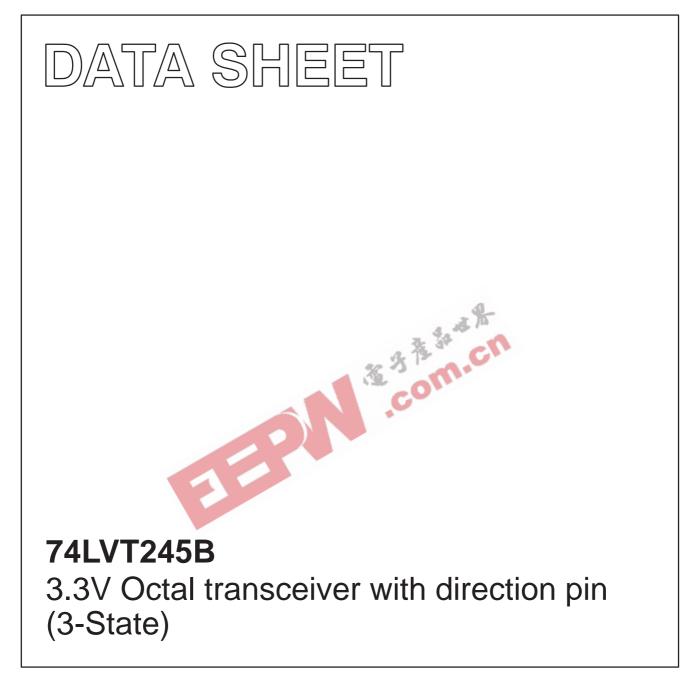
INTEGRATED CIRCUITS



Product specification

1999 Mar 19

IC23 Data Handbook



74LVT245B

FEATURES

- Octal bidirectional bus interface
- 3-State buffers
- Output capability: +64mA/-32mA
- TTL input and output switching levels
- Input and output interface capability to systems at 5V supply
- Bus-hold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Live insertion/extraction permitted
- Power-up 3-State
- No bus current loading when output is tied to 5V bus
- Latch-up protection exceeds 500mA per JEDEC Std 17
- ESD protection exceeds 2000V per MIL STD 883 Method 3015 and 200V per Machine Model

DESCRIPTION

The LVT245B is a high-performance BiCMOS product designed for V_{CC} operation at 3.3V.

This device is an octal transceiver featuring non-inverting 3-State bus compatible outputs in both send and receive directions. The control function implementation minimizes external timing requirements. The device features an Output Enable (\overline{OE}) input for easy cascading and a Direction (DIR) input for direction control.

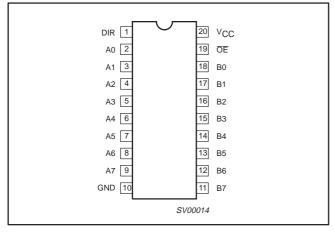
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UICK REFER	ENCE DATA	3, 15, 14				
SYMBOL	PARAMETER	PARAMETER CONDITIONS T _{amb} = 25°C; GND = 0V		UNIT		
t _{PLH} t _{PHL}	Propagation delay An to Bn or Bn to An	C _L = 50pF; V _{CC} = 3.3V	2.4	ns		
C _{IN}	Input capacitance DIR, OE	V ₁ = 0V or 3.0V	4	pF		
C _{I/O}	I/O pin capacitance	Outputs disabled; $V_{I/O} = 0V \text{ or } 3.0V$	10	pF		
I _{CCZ}	Total supply current	Outputs disabled; V _{CC} = 3.6V	0.13	mA		

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	ORDERING INFORMATION	DWG NUMBER
20-Pin Plastic SO	–40°C to +85°C	74LVT245B D	SOT163-1
20-Pin Plastic SSOP	-40°C to +85°C	74LVT245B DB	SOT339-1
20-Pin Plastic TSSOP	-40°C to +85°C	74LVT245B PW	SOT360-1

PIN CONFIGURATION

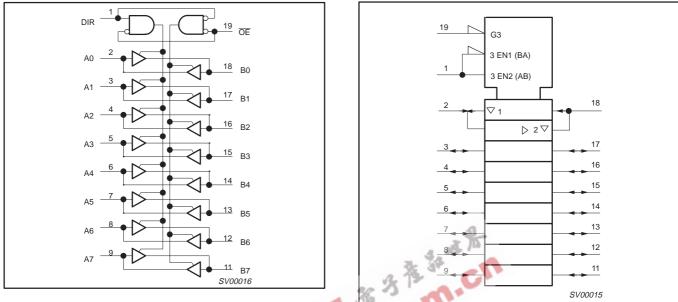


PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1	DIR	Direction control input
2, 3, 4, 5, 6, 7, 8, 9	A0 – A7	Data inputs/outputs (A side)
18, 17, 16, 15, 14, 13, 12, 11	B0 – B7	Data inputs/outputs (B side)
19	ŌĒ	Output enable input (active–Low)
10	GND	Ground (0V)
20	V _{CC}	Positive supply voltage

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LOGIC SYMBOL



LOGIC SYMBOL (IEEE/IEC)

FUNCTION TABLE

INP	UTS	INPUTS/C	DUTPUTS
OEn	DIR	An	Bn
L	L	An= Bn	Inputs
L	Н	Inputs	Bn =An
Н	Х	Z	Z

H = High voltage level

L = Low voltage level

X = Don't care Z = High impedance "Off" state

ABSOLUTE MAXIMUM RATINGS^{1,2}

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +4.6	V
I _{IK}	DC input diode current	V ₁ < 0	-50	mA
VI	DC input voltage ³		-0.5 to +7.0	V
I _{ОК}	DC output diode current	V _O < 0	-50	mA
V _{OUT}	DC output voltage ³	Output in Off or High state	-0.5 to +7.0	V
		Output in Low state	128	
lout	DC output current	Output in High state	-64	mA
T _{stg}	Storage temperature range		-65 to +150	°C

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction

the performance expansion of a high performance megatical encount incomparation much deriver and output comparation of the performance encount of the performance encount

74LVT245B

SYMBOL	PARAMETER	LIM	ITS	UNIT
STMBOL	FARAMETER	MIN	UNIT	
V _{CC}	DC supply voltage	2.7	3.6	V
VI	Input voltage	0	5.5	V
V _{IH}	High-level input voltage	2.0		V
V _{IL}	Input voltage		0.8	V
I _{ОН}	High-level output current		-32	mA
lai	Low-level output current		32	mA
IOL	Low-level output current; current duty cycle \leq 50%; f \geq 1kHz		64	
Dt/Dv	Input transition rise or fall rate; Outputs enabled		10	ns/V
T _{amb}	Operating free-air temperature range	-40	+85	°C

RECOMMENDED OPERATING CONDITIONS

DC ELECTRICAL CHARACTERISTICS

			a.		LIMITS		
SYMBOL PARAMETER		TEST CONDITIONS		Temp = -40°C to +85°C			UNIT
		4	- 3ª	MIN	TYP ¹	MAX	
V _{IK}	Input clamp voltage	$V_{CC} = 2.7V; I_{IK} = -18mA$	9 CT		-0.9	-1.2	V
		$V_{CC} = 2.7$ to 3.6V; $I_{OH} = -100\mu A$	ALC: N	V _{CC} -0.2	V _{CC} -0.1		
V _{OH}	High-level output voltage	V _{CC} = 2.7V; I _{OH} = -8mA		2.4	2.5		V
	$V_{CC} = 3.0V; I_{OH} = -32mA$		2.0	2.2			
		V _{CC} = 2.7V; I _{OL} = 100μA			0.1	0.2	
		V _{CC} = 2.7V; I _{OL} = 24mA			0.3	0.5	
V _{OL}	Low-level output voltage	V _{CC} = 3.0V; I _{OL} = 16mA			0.25	0.4	V
		$V_{CC} = 3.0V; 1_{OL} = 32mA$			0.3	0.5	
		V _{CC} = 3.0V; I _{OL} = 64mA			0.4	0.55	
		$V_{CC} = 0 \text{ or } 3.6 \text{V}; \text{ V}_{\text{I}} = 5.5 \text{V}$	Control pins		1	10	
		$V_{CC} = 3.6V; V_I = V_{CC} \text{ or } GND$			±0.1	±1	μΑ
I _I	Input leakage current	$V_{CC} = 3.6V; V_{I} = 5.5V$			1	20	
		$V_{CC} = 3.6V; V_I = V_{CC}$	I/O Data pins ⁴		0.1	1	
		$V_{CC} = 3.6V; V_{I} = 0$	1		-1	-5	
I _{OFF}	Output off current	$V_{CC} = 0V$; V_{I} or $V_{O} = 0$ to 4.5V	_		1	±100	μA
		$V_{CC} = 3V; V_{I} = 0.8V$		75	150		
I _{HOLD}	Bus Hold current A inputs ⁵	$V_{CC} = 3V; V_{I} = 2.0V$		-75	-150		μA
		$V_{CC} = 0V$ to 3.6V; $V_{CC} = 3.6V$		±500			
I_{EX}	Current into an ouptut in the High state when $V_O > V_{CC}$	V _O = 5.5V; V _{CC} = 3.0V			60	125	μΑ
I _{PU/PD}	Power up/down 3-State output current ³	$V_{CC} \le 1.2$ V; $V_{O} = 0.5$ V to V_{CC} ; $V_{I} = GNE OE/OE = Don't care$	D or V _{CC} ;		15	±100	μA
I _{CCH}		$V_{CC} = 3.6V$; Outputs High, $V_I = GND$ or	V _{CC} , I _{O =} 0		0.13	0.19	
I _{CCL}	Quiescent supply current	$V_{CC} = 3.6V$; Outputs Low, $V_{I} = GND$ or V_{I}	/ _{CC,} I _{O =} 0		3	12	mA
I _{CCZ}	1	V_{CC} = 3.6V; Outputs Disabled; V_I = GNE	D or V_{CC} , $I_{O} = 0$		0.13	0.19	
ΔI_{CC}	Additional supply current per input pin ²	$V_{CC} = 3V$ to 3.6V; One input at V_{CC} -0.6V Other inputs at V_{CC} or GND	V,		0.1	0.2	mA

NOTES:

NOTES:
All typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.
This is the increase in supply current for each input at the specified voltage level other than V_{CC} or GND
This parameter is valid for any V_{CC} between 0V and 1.2V with a transition time of up to 10msec. From V_{CC} = 1.2V to V_{CC} = 3.3V ± 0.3V a transition time of 100µsec is permitted. This parameter is valid for T_{amb} = +25°C only.
Unused pins at V_{CC} or GND.
This is the bus hold overdrive current required to force the input to the opposite logic state.

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AC CHARACTERISTICS

GND = 0V; $t_R = t_F = 2.5ns$; $C_L = 50pF$; $R_L = 500\Omega$; $T_{amb} = -40^{\circ}C$ to +85°C.

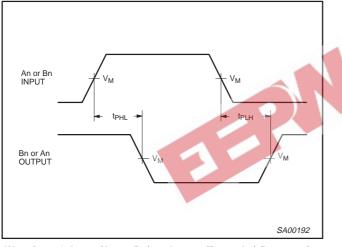
				LIMITS			
SYMBOL	PARAMETER	WAVEFORM	Vco	c = 3.3V +0	.3V	V _{CC} = 2.7V	UNIT
			MIN	TYP ¹	MAX	MAX	
t _{PLH} t _{PHL}	Propagation delay An to Bn or Bn to An	1	1.2 1.2	2.4 2.4	3.5 3.5	4.0 4.0	ns
t _{PZH} t _{PZL}	Output enable time to High and Low level	2	1.3 1.7	3.3 3.2	5.5 5.5	7.1 6.5	ns
t _{PHZ} t _{PLZ}	Output disable time from High and Low Level	2	2.2 2.2	3.6 3.4	5.9 5.0	6.5 5.1	ns

NOTES:

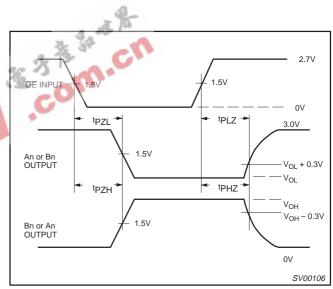
1. All typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.

AC WAVEFORMS

 V_{M} = 1.5V, V_{IN} = GND to 2.7V



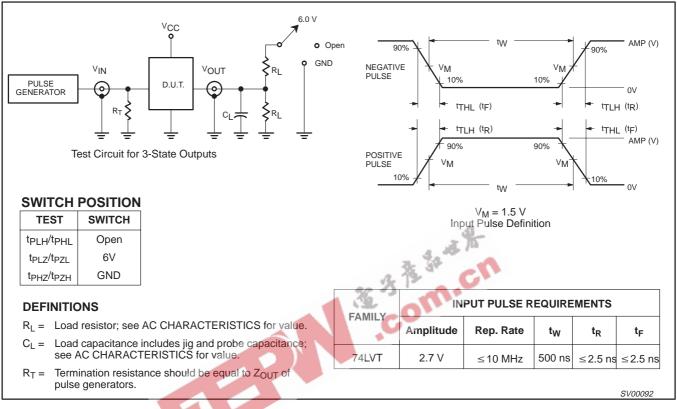
Waveform 1. Input (An or Bn) to Output (Bn or An) Propagation Delays



Waveform 2. 3-State Output Enable and Disable Times

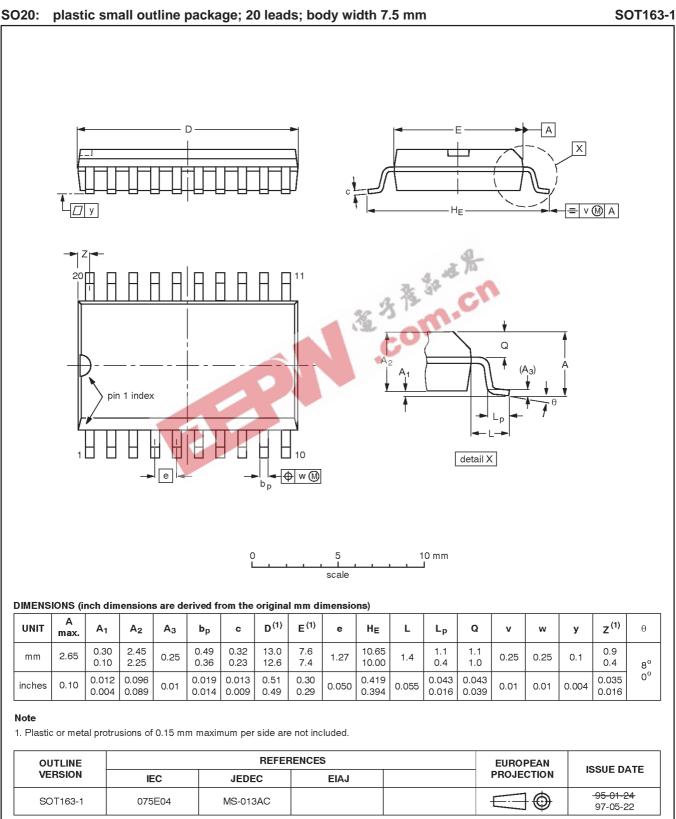
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TEST CIRCUIT AND WAVEFORMS

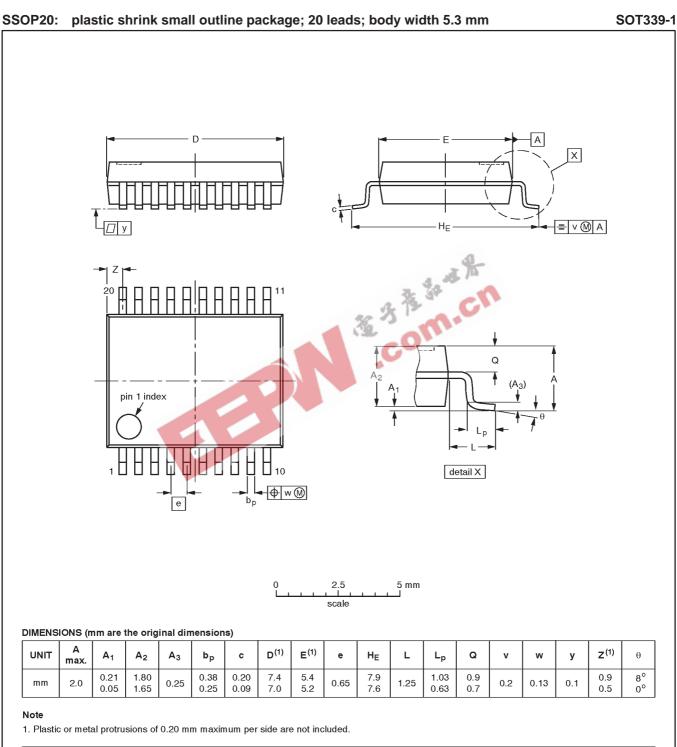


74LVT245B

3.3V Octal transceiver with direction pin (3-State)



SO20:



	REFER	ENCES			
IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE	
	MO-150AE			-93-09-08- 95-02-04	
_	IEC	IEC JEDEC	IEC JEDEC EIAJ	IEC JEDEC EIAJ PROJECTION	

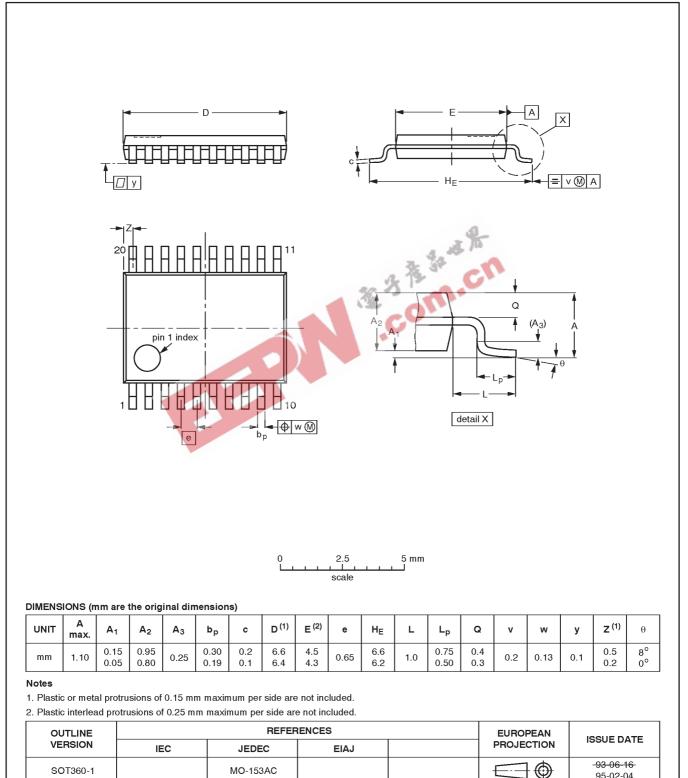
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95-02-04

3.3V Octal transceiver with direction pin (3-State)





74LVT245B

Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
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Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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